Trying 3106016892...Open

Welcome to STN International! Enter x:x
LOGINID:ssspta1653jxl
PASSWORD:

TERMINAL (ENTER 1, 2, 3, OR ?):2

Welcome to STN International 2 NEWS Feb Web Page URLs for STN Seminar Schedule - N. America NEWS Dec 17 Expanded CAplus Coverage of US, Japanese, WIPO, EPO, and German patents NEWS Feb 1 Addition of Machine-Translated Abstracts to CAplus Feb 28 NEWS Patent Information Now Searchable in CAOLD Mar 20 NEWS INPADOC: PRODUCER WARNING ABOUT DATA DELAYS Mar 22 NEWS NEW FEATURES IN INPADOC - RANGE SEARCHING AND NEW SDI/UPDATE SEARCH FIELD NEWS May Beilstein Abstracts on STN - FILE BABS NEWS May 1 RN CROSSOVER AND ANSWER SIZE LIMITS INCREASED NEWS May 1 AIDSLINE has been reloaded May 1 May 9 NEWS 10 Searching Y2-K compliant Patent Numbers NEWS 11 Sequence Similarity Batch Search in DGENE NEWS 12 May 19 Weekly Statistics for New Entries now available in INPADOC NEWS 13 May 22 CITED REFERENCES NOW AVAILABLE IN CAPLUS AND CA FILE NEWS 14 May 22 POSTPROCESSING OF SEARCH RESULTS MAY BE AFFECTED BY ADDITION OF CITED REFERENCES TO CAPLUS, CA, REGISTRY, CASREACT, MARPAT, and MARPATPREV NEWS 15 Jun KOREAN PATENTS NOW IN CAS DATABASES NEWS 16 Jun 20 WIPO/PCT Patents Fulltext Database now on STN NEWS EXPRESS FREE UPGRADE 5.0C NOW AVAILABLE NEWS HOURS STN Operating Hours Plus Help Desk Availability General Internet Information NEWS INTER NEWS LOGIN Welcome Banner and News Items NEWS PHONE Direct Dial and Telecommunication Network Access to STN CAS World Wide Web Site (general information) NEWS WWW

Enter NEWS followed by the item number or name to see news on that specific topic.

All use of STN is subject to the provisions of the STN Customer agreement. Please note that this agreement limits use to scientific research. Use for software development or design or implementation of commercial gateways or other similar uses is prohibited and may result in loss of user privileges and other penalties.

FILE 'HOME' ENTERED AT 14:27:22 ON 22 JUN 2000

=> file biosis caplus medline scisearch

COST IN U.S. DOLLARS

FULL ESTIMATED COST ENTRY SESSION 0.15 0.15

SINCE FILE

TOTAL

FILE 'BIOSIS' ENTERED AT 14:27:47 ON 22 JUN 2000 COPYRIGHT (C) 2000 BIOSIS(R)

FILE 'CAPLUS' ENTERED AT 14:27:47 ON 22 JUN 2000 USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT. PLEASE SEE "HELP USAGETERMS" FOR DETAILS. COPYRIGHT (C) 2000 AMERICAN CHEMICAL SOCIETY (ACS)

FILE 'MEDLINE' ENTERED AT 14:27:47 ON 22 JUN 2000

```
FILE 'SCISEARCH' ENTERED AT 4:27:47 ON 22 JUN 2000
COPYRIGHT (C) 2000 Institute for Scientific Information (ISI) (R)
=> s dlc and (sensor or biosensor)
            21 DLC AND (SENSOR OR BIOSENSOR)
=> s l1 and (waveguide or optic? or spr or plasmon)
             O L1 AND (WAVEGUIDE OR OPTIC? OR SPR OR PLASMON)
=> dup rem 11
PROCESSING COMPLETED FOR L1
             15 DUP REM L1 (6 DUPLICATES REMOVED)
=> d 13 bib ab 1-15
L3
     ANSWER 1 OF 15 CAPLUS COPYRIGHT 2000 ACS
     2000:400754 CAPLUS
AN
     Adhesion strength of DLC films on glass with mixing layer
TI
     prepared by IBAD
     Funada, Y.; Awazu, K.; Yasui, H.; Sugita, T.
ΑU
     Kanazawa, Tomizu-machi, Ro-1, Industrial Research Institute of Ishikawa, ,
CS
     920-0233, Ishikawa, Japan
     Surf. Coat. Technol. (2000), 128-129, 308-312
SO
     CODEN: SCTEEJ; ISSN: 0257-8972
PΒ
     Elsevier Science S.A.
DT
     Journal
LA
     English
AB
     The improvement of the adhesion of diamond-like carbon (DLC)
     films has been tried by ion beam assisted deposition (IBAD).
                                                                   The adhesion
     strength must be quant. evaluated and detd. in order to confirm the
     improving effect of the adhesion of DLC films by IBAD. In this
     study, DLC films were prepd. on a glass substrate with a mixing
     layer prepd. by IBAD. For the samples, the scratch tests were carried out
     using a scratch tester with a CCD camera and two AE sensors.
     The detachment process of the DLC film during a scratch test was
     obsd. and the detachment area was measured. On the other hand, AE signals
     were detected corresponding to the detachment of the DLC film,
     and the force causing the detachment was detd. by analyzing the signals.
     The adhesion strength of DLC films was calcd. from the
     detachment area and the force. From that result, the adhesion strength of
     DLC films without a mixing layer was 3.2 MPa. When the mixing
     layer was formed by IBAD with a condition of Ar-30 kV and 2.1 .mu.A/cm2,
     the adhesion strength increased to 10.7 MPa. Furthermore, that increased
     up to 44 MPa in the case of 21.0 .mu.A/cm2. Therefore, it was realized
     that IBAD improved the adhesion of DLC films and the effects
     were made clear quant.
L3
    ANSWER 2 OF 15 CAPLUS COPYRIGHT 2000 ACS
AN
     1999:659567 CAPLUS
DN
     131:280795
TΙ
     Sensor devices and methods for using them
ΙN
     Vadgama, Pankaj Madganlal; Warriner, Keith Stewart Robert
PΑ
     The Victoria University of Manchester, UK
SO
     PCT Int. Appl., 26 pp.
     CODEN: PIXXD2
DT
     Patent
    English
LA
FAN.CNT 1
    PATENT NO.
                    KIND DATE
                                          APPLICATION NO. DATE
PΙ
    WO 9951973
                     A1 19991014
                                          WO 1999-GB985 19990330
        W: AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE,
            DK, EE, ES, FI, GB, GE, GH, GM, HR, HU, ID, IL, IS, JP, KE, KG,
             KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX,
```

```
NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, J, TM, TR, TT, UA, UG, US, UI VN, YU, ZW, AM, AZ, BY, KG, KZ, D, RU, TJ, TM RW: GH, GM, KE, LS, MW, SD, SL, SZ, UG, ZW, AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG
                      A1 19991006 GB 1998-7112
A1 19991025 AU 1999-3159
     GB 2335985
                                                                 19980403
     AU 9931599
                                              AU 1999-31599
                                                                 19990330
PRAI GB 1998-7112
                        19980403
     WO 1999-GB985
                       19990330
     Copper electrodes coated on their surface with diamond-like carbon (
     DLC), and their use in electrolytic devices and procedures.
     diamond-like carbon coating, usually <5 .mu. thick, enables the benefits
     of copper electrodes to be obtained in media less alk. than the highly
     alk. ones usually required for bare copper electrodes. The copper may be
     solid or carried as a surface layer upon a carrier of any desired shape or
     degree of cond. or strength. The coated electrodes are esp. advantageous
     as working electrodes in sensors and methods for electrochem.
     anal. and particularly for detn. of analytes which undergo reaction, esp.
     oxidn., at copper electrodes. They have especial value for electro-anal.
     of hydroxylated compds., esp. those relatively resistant to electrolytic
     oxidn. (e.g. sugars and ethanol) and their operability at less alk. pH
     enables convenient and easy monitoring of fermn. processes.
RE.CNT
RE
(1) Chen, Z; JOURNAL OF CHROMATOGRAPHY A 1997, V766 CAPLUS
(2) Univ Manchester; WO 9324828 A 1993
(3) Yamamoto, K; US 4797527 A 1989 CAPLUS
L3
     ANSWER 3 OF 15 CAPLUS COPYRIGHT 2000 ACS
AN
     1999:388357 CAPLUS
DN
     131:27253
TΙ
     Electrochemical sensor devices and methods for using them
ΙN
     Vadgama, Pankaj Madganlal; Warriner, Keith Stewart Robert
PΑ
     The Victoria University of Manchester, UK
SO
     PCT Int. Appl., 26 pp.
     CODEN: PIXXD2
DT
     Patent
LA
     English
FAN.CNT 1
                   KIND DATE
     PATENT NO.
                                             APPLICATION NO. DATE
                                            WO 1998-GB3585 19981201
PΙ
     WO 9930143
                       Al 19990617
         W: AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE,
              DK, EE, ES, FI, GB, GE, GH, GM, HR, HU, ID, IL, IS, JP, KE, KG,
              KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX,
              NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM
         RW: GH, GM, KE, LS, MW, SD, SZ, UG, ZW, AT, BE, CH, CY, DE, DK, ES,
              FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, BF, BJ, CF, CG, CI,
              CM, GA, GN, GW, ML, MR, NE, SN, TD, TG
     GB 2332058 A1 19990609 GB 1997-25707
                                                               19971205
     AU 9913434
                                             AU 1999-13434
                        A1
                              19990628
                                                                 19981201
PRAI GB 1997-25707
                      19971205
     GB 1998-18509
                       19980826
     WO 1998-GB3585
                       19981201
AΒ
     Sensor devices for electrolytic anal. of liq. media, comprising
     a working electrode coated with an amino acid polymer (preferably
     poly-lysine on platinum), advantageously with a diffusion-lowering barrier
     layer of an applied or deposited thin porous or permeable layer of org.
     polymer or inorg. material superimposed upon it which allows analytes to
     pass through. The barrier coating stabilizes the poly-amino acid coating
     against dislodgement by acidic media and the poly-amino acid/covering
     barrier combination gives a sensor having enough stability to be
     heat-sterilized, good pH independence and selectivity with minimal
     interference by other components, and long user life. Preferred barrier
     materials are PVC, (which can be applied from soln., e.g. dip-coating) and
     diamond-like carbon (DLC), preferably 5.mu.m thick or less. The
     electro-anal. procedure preferred is pulsed amperometric detection (PAD).
```

The sensors are esp. effective for ethanol detn., and applicable

to monitoring and measurement of fermn. media with reduced interference by any sugars present. RE.CNT 5 RE (1) Hiroko, K; US 5281319 A 1994 (2) Pickett, C; J CHEM SOC DALTON TRANS 1994, V14, P2181 (3) Toray Industries; EP 0266432 A 1988 (4) Vadgama, P; WO 9324828 A 1993 (5) Watkins, B; JOURNAL OF THE AMERICAN CHEMICAL SOCIETY 1975, V97(12), P3549 CAPLUS ANSWER 4 OF 15 CAPLUS COPYRIGHT 2000 ACS L3 1999:127046 CAPLUS ΑN DN 130:150618 Ion-sensitive sensor devices with diamond-like carbon coating TΙ and analytical methods using them Vadgama, Pankaj Madganlal; Warriner, Keith Stewart Robert ΙN The Victoria University of Manchester, UK PΑ SO PCT Int. Appl., 22 pp. CODEN: PIXXD2 DTPatent English LA FAN.CNT 1 PATENT NO. KIND DATE APPLICATION NO. DATE WO 9907878 A1 19990218 WO 1998-GB2301 19980731 PΙ W: AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ, DE, DK, EE, ES, FI, GB, GE, GH, GM, HR, HU, ID, IL, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG, MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK, SL, TJ, TM, TR, TT, UA, UG, US, UZ, VN, YU, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM RW: GH, GM, KE, LS, MW, SD, SZ, UG, ZW, AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, BF, BJ, CF, CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG GB 1997-16749 GB 2328023 A1 19990210 19970808 AU 9886360 A119990301 AU 1998-86360 19980731 19970808 PRAI GB 1997-16749 WO 1998-GB2301 19980731 AB Disclosed are improved sensor devices responsive to ionic changes, and esp. pH changes, of media in contact with them, wherein the sensor element is coated with diamond-like carbon, and anal. methods for their use. The device is esp. applicable to systems in which the pH change measured is the result of enzyme action, particularly by formation of a basic product, for example using urease as the enzyme to form ammonia from urea. The preferred sensor element is a solid-state device, notably an enzyme field effect transistor in which the enzyme is bound on the surface of a semiconductor in conjunction with a conducting polymer, preferably polypyrrole. Detns. are usually made by measurement of the impedance of the sensor when in contact with a buffered soln. of the sample to be examd., and can be used for detg. urea levels in blood. A urea-sensitive urease/polypyrrole impedimetric sensor was prepd. having immobilized urease and an outer coating of diamond-like carbon (DLC). Sensors with the DLC coating had lower responses to urea than those not coated, but, more importantly, they were almost independent of soln. buffering capacity (content of buffer salts). RE.CNT (1) Higson, S; Analytica Chimica Acta 1993, V271(1), P125 (2) Ici Plc; EP 0503943 A 1992 (3) Thermo Fast U K Limited; WO 9810288 A 1998 (4) Univ Manchester; WO 9324828 A 1993

- ANSWER 5 OF 15 CAPLUS COPYRIGHT 2000 ACS L3
- AN1999:363349 CAPLUS
- DN 131:78853
- TΙ Surface phenomena of the thin diamond-like carbon films
- Polyakov, V. I.; Rukovishnikov, A. I.; Khomich, A. V.; Druz, B. L.; Kania, ΑU D.; Hayes, A.; Prelas, M. A.; Tompson, R. V.; Ghosh, T. K.; Loyalka, S. K.

- CS Institute of Radio Eng. and Electronics, RAS, Moscow, 193907, Russia SO Mater. Res. Soc. Symptococ. (1999), 555(Properties and Processing of Vapor-Deposited Coatings), 345-350 CODEN: MRSPDH; ISSN: 0272-9172
- PB Materials Research Society
- DT Journal
- LA English
- Diamond-like carbon films (DLC) 10-40 nm thick were deposited on quartz substrates on an interdigitated planar array of 20 .mu.m Ni electrodes already prepd. by lithog. techniques. The influence of the adsorbed mols. on the elec. properties of the thin DLC films was investigated. Current and capacitance-voltage characteristics were examd. Charge-based deep level transient spectroscopy (Q-DLTS) was used for study of adsorption and desorption processes. The strong sensitivity of Q-DLTS spectra to the presence of the vapor water and iso-Pr alc. was found. For example, the Q-DLTS signal for some deposited DLC film was changed more then in order in presence of the water vapor. Such strong surface phenomena of the thin DLC films may be exploited in novel gas sensor devices.

RE.CNT 9

RE

- (1) Arora, B; J Appl Phys 1993, V73, P1802 CAPLUS
- (2) Druz, B; Mater Res Soc Proc 1997, V446, P413 CAPLUS
- (3) Druz, B; Surface Coatings Technol 1996, V86-87, P708 CAPLUS
- (4) Lang, D; J Appl Phys 1974, V45, P3023 CAPLUS
- (5) Pimenov, S; Diamond and Related Materials 1997, V6, P1650 CAPLUS
- ALL CITATIONS AVAILABLE IN THE RE FORMAT
- L3 ANSWER 6 OF 15 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 1
- AN 1998:591952 CAPLUS
- DN 129:305605
- TI The mass recognizing property of **DLC** [diamond-like carbon] film for formic acid vapors
- AU Yan, Yonghong; Zeng, Yun; Xiang, Jiannan; Yin, Xia; Jin, Jiucheng; Che, Zengzhang
- CS Dep. Physics, Institute Chem., Hunan Univ., Changsha, 410082, Peop. Rep. China
- SO Chin. Sci. Bull. (1998), 43(15), 1307-1311 CODEN: CSBUEF; ISSN: 1001-6538
- PB Science in China Press
- DT Journal
- LA English
- AB The carbon films are prepd. by r.f. plasma method with n-butylamine as carbon source. The anal. of Raman spectroscopy shows that this kind of carbon film has diamond-like structure, and IR spectroscopy measurement indicates that there are SP2 bonding, SP3 bonding and amino-group in the film. It is the existence of amino-group and hydrogen atom that cause the amorphous structure and the deformation of bonding to increase, thus leading the Raman spectrum to form a broad absorption band. The quartz crystal microbalance (QCM) deposited with this kind of carbon film as recognizing coating is very sensitive to formic acid vapors. This QCM sensor has good reproducibility, high stability, rapid response and long lifetime.
- L3 ANSWER 7 OF 15 CAPLUS COPYRIGHT 2000 ACS
- AN 1999:239359 CAPLUS
- DN 130:331910
- TI Electronic characterization of thin diamond like carbon films for pHsensor applications
- AU Schitthelm, Frank; Rover, Kai-Sven; Ferretti, Rudiger
- CS Institut fur Halbleitertechnologie und Werkstoffe der Elektrotechnik, University of Hannover, Hannover, 30167, Germany
- SO Proc. SPIE-Int. Soc. Opt. Eng. (1998), 3539(Chemical Microsensors and Applications), 139-146
 CODEN: PSISDG; ISSN: 0277-786X
- PB SPIE-The International Society for Optical Engineering
- DT Journal
- LA English
- AB Amorphous Diamond like carbon (DLC) thin films were deposited on

to 4"-silicon wafers by an electron cyclotron resonance (ECR) microwave excited methane (CH4) ethyne (C2H2) plasma at low produce. Electro characterization of DLC films were performed by I/V and C/V sure. Electronic measurements using MIS-structures. Whereas the electrochem. pH-characteristics were measured using ion-sensitive field-effect transistors (ISFET). It is shown, that the type of carrier transport mechanism in DLC films depends on the process conditions and that the elec. cond. varies over a wide range. This can be adjusted mainly by the kinetic energy of the CxHx+ ions and the C to H ratio, which depends on the type of process gas. The dominant charge transport mechanism in DLC films based on a methane plasma is the Poole-Frenkel emission whereas the charge flow for ethyne based DLC films is space-charge limited. The electronic cond. of DLC films deposited with ethyne as process gas is typically about five orders of magnitude higher than methane based films. The electrochem. characterization shows a pH-sensitivity at 50-57 mV/pH and a long-term pH signal stability at 0.3-25 .mu.V/h. Based on the different pH-sensitivities it will be possible to produce a pH-sensor in differential mode using DLC/DLC or DLC/Ta205 combinations for the sensitive layers.

RE.CNT 12

RE

- (1) Barbottin, G; Instabilities in silicon devices 1986, V1(ISBN 0 444 87944 7)
- (3) Cho, N; J Mater Res 1990, V5(11), P2543 CAPLUS
- (5) Dowling, D; Surf Coat Technol 1992, V53, P177 CAPLUS
- (8) Ianno, N; Appl Phys Commun 1993, V12(1), P105 CAPLUS
- (10) Raveh, A; Surf Coat Technol 1992, V53, P275 CAPLUS
- ALL CITATIONS AVAILABLE IN THE RE FORMAT
- L3 ANSWER 8 OF 15 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 2
- AN 1998:86033 CAPLUS
- DN 128:162257
- TI Diamond-like carbon-gate pH-ISFET
- AU Voigt, H.; Schitthelm, F.; Lange, T.; Kullick, T.; Ferretti, R.
- CS Institut fur Halbleitertechnologie und Werkstoffe der Elektrotechnik, University of Hannover, Hannover, 30167, Germany
- SO Sens. Actuators, B (1997), B44(1-3), 441-445 CODEN: SABCEB; ISSN: 0925-4005
- PB Elsevier Science S.A.
- DT Journal
- LA English
- AB A novel chem.-resistant ion-selective field-effect transistor (ISFET) array is introduced, using amorphous diamond-like C (DLC) films for passivation and as pH-sensitive layer. A DLC coating technol. is developed, useful for depositing and patterning final thin film on active and passive surfaces of ISFET devices. The DLC films are produced by a low-temp. dual radiofrequency methane-He gas mixt. plasma. DLC thin films show complete chem. inert behavior in aggressive aq. electrolytes. The high film hardness in addn. to the chem. inert behavior makes DLC films more suitable as passivation layers for sensor devices than other materials (i.e. Si3N4, SiO2, etc.). It is shown from the results of electrochem. and electronic characterization of ISFET devices with DLC thin films that DLC is suitable for sensor applications. A comparative characterization of DLC-coated ISFET with a Ta2O5-coated ISFET on a single chip **sensor** is shown. The pH response of the DLC ISFET shows lower drift than that of the Ta2O5-coated ISFET. No redox cross-sensitivity was found or DLC-coated ISFET. shift of the sensor response is only slightly dependent on temp.
- L3 ANSWER 9 OF 15 CAPLUS COPYRIGHT 2000 ACS
- AN 1997:589266 CAPLUS
- DN 127:265003
- TI Development of plasma technology for high performance carbon materials from natural gas
- AU Yu, Zuo-Long; Zhou, Kun-Lin; Cao, Wei-Min; Zeng, Da-Quan; Chen, Mian-Zhong; Zhou, Gu-Min; Zhang, Xiang-Fu; Zhang, Yong
- CS Chengdu Institute of Organic Chemistry, The Chinese Academy of Sciences, Chengdu, 610041, Peop. Rep. China

- SO J. Nat. Gas Chem. (1997), 6(3), 175-187 CODEN: JGCHE8; ISSN: 18-9953
- PB Chengdu Institute of Organic Chemistry, Academia Sinica
- DT Journal LA English
- AB Ultrafine carbon particle and diamond like carbon film, compounded carbon with Ti, Si, Sn, Ni, Pt etc., may have superb characteristics in hardness, lubrication, heat cond., photo-transmissivity, semicond. etc. The carbon materials were prepd. from natural gas by using plasma. The type of plasma, working atm. and conditions have been studied. The properties and applications of some typical ultrafine carbon particles and diamond like carbon films were also discussed.
- L3 ANSWER 10 OF 15 CAPLUS COPYRIGHT 2000 ACS
- AN 1997:229994 CAPLUS
- TI Micromachining.
- AU De Rooij, N. F.
- CS Institute Microtechnology, University Neuchatel, Neuchatel, CH-2007, Switz.
- SO Book of Abstracts, 213th ACS National Meeting, San Francisco, April 13-17 (1997), BTEC-008 Publisher: American Chemical Society, Washington, D. C. CODEN: 64AOAA
- DT Conference; Meeting Abstract
- LA English
- AB Recent progress in micromachining of several materials will be reviewed, focusing on single crystal silicon, quartz and glass. In particular the importance of these materials for the construction of miniaturized chem. anal. systems will be outlined. Representative examples of chem. anal. systems using micromachining techniques will be presented including (1) ion-analyzers, (2) a bioreactor for space research, (3) nanotitrators. Also recent developments in amperometric chem. sensors using diamond like carbon (DLC) thin films will be discussed.
- L3 ANSWER 11 OF 15 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 3
- AN 1995:286284 CAPLUS
- DN 122:75827
- TI Diamond like carbon films for enzyme electrodes; characterization of novel overlying permselective barriers
- AU Higson, Seamus P. J.; Vadgama, Pankaj M.
- CS Department of Medicine (Section of Clinical Biochemistry), University of Manchester, Hope Hospital, Eccles Old Road, Salford, M6 8HD, UK
- SO Anal. Chim. Acta (1995), 300(1-3), 85-90 CODEN: ACACAM; ISSN: 0003-2670
- DT Journal
- LA English
- Diamond like carbon (DLC) coated microporous polycarbonate
 membranes have been studied for use as novel composite permselective
 barriers membranes for a glucose enzyme electrode. Permeability coeffs.,
 P, for key electrochem. active interferents across uncoated and
 DLC coated polycarbonate membranes has been compared. Interferent
 responses have then been assessed for sensors incorporating such
 membranes, and their relationship to differing DLC depositions
 assessed. Membranes with smaller pore sizes (0.03 and 0.01 .mu.m) and
 extended DLC depositions (up to 7 min coating), while imparting
 some enhanced selectivity towards glucose, failed to show major
 discrimination for glucose over interferents as shown by P values: max.
 glucose-to-interferent P ratios being 1.36 and 1.25 for ascorbate and
 urate, resp. The implications of these findings are discussed.
- L3 ANSWER 12 OF 15 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 4
- AN 1995:286283 CAPLUS
- DN 122:75826
- TI Diamond-like carbon coated films for enzyme electrodes; characterization of biocompatibility and substrate diffusion limiting properties
- AU Higson, Seamus P. J.; Vadgama, Pankaj M.
- CS Department of Medicine (Section of Clinical Biochemistry), University of Manchester, Hope Hospital, Eccles Old Rd., Salford, M6 8HD, UK
- SO Anal. Chim. Acta (1995), 300(1-3), 77-83 CODEN: ACACAM; ISSN: 0003-2670

DT Journal LA. English

AB

The biocompatibility and substrate diffusion limiting properties for a range of diamond like carbon (DLC) coated microporous polycarbonate and DLC-coated dialysis (hemodialysis) membranes were studied. This characterization builds upon previous findings where DLC coated membranes imparted enhanced enzyme electrode performance. In this study, electrode linear ranges were extended from 10 mM glucose for a 0.01 .mu.m pore size membrane to 160 mM. correlated with the duration of DLC deposition and assocd. redns. in permeability for glucose. Permeability coeff. ratios for both microporous and dialysis membranes were also found to be important with low glucose/O2 permeability ratios imparting extensions in glucose linear response range. DLC-coated membranes employed within enzyme electrodes have also been shown to exhibit enhanced hemocompatibility as detd. by both sensitivity change and surface deposition of blood components examd, by SEM. Correlations are made between the reduced losses in sensor response to biofouling/working electrode passivation processes, and extended linear ranges that DLC coated membranes may impart to enzyme electrode performance. Particular ref. is made to the detn. of glucose levels within whole blood.

L3 ANSWER 13 OF 15 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 5

AN 1994:522446 CAPLUS

DN 121:122446

TI The properties of diamond-like carbon layers deposited onto SiO2 aerogel

AU Mitura, E.; Wawrzyniak, P.; Rogacki, G.; Szmidt, J.; Jakubowski, A.

CS Faculty of Process and Environmental Engineering, Technical University of Lodz, Wolczanska 175, Lodz, 90-924, Pol.

SO Diamond Relat. Mater. (1994), 3(4-6), 868-70 CODEN: DRMTE3

DT Journal

LA English

Possible prodn. of an SiO2 aerogel coated with diamond-like carbon (AΒ DLC) by the r.f. decompn. of methane is presented. The silica gel was obtained by hydrolysis and condensation of tetraethoxysilane. A two-step method was used. One set of gel samples was heated in the autoclave filled with alc. and decompressed isothermally after reaching the crit. point of the solvent. Another set was subjected to supercrit. extn. of alc. by carbon dioxide followed by isothermal decompression at a temp. higher than the crit. temp. of CO2 (304.2 K). In the processes described transparent aerogels of d. 104-115 kg m-3 were obtained. The influence of DLC coating on the mech. strength of the DLC-SiO2 aerogel system is presented. The DLC layer was deposited onto two surfaces of an aerogel plate by r.f. plasma chem. vapor deposition. The DLC films are very hard and resistant to acids and bases. DLC, which is semitransparent for mass transfer, is a good material for sensors. Together with the aerogel substrate the DLC film creates a structure which is very promising for electronics.

L3 ANSWER 14 OF 15 CAPLUS COPYRIGHT 2000 ACS

AN 1995:876884 CAPLUS

DN 123:320511

TI Automotive applications of diamond and diamondlike materials

AU Tamor, Michael A.

CS Research Laboratory, Ford Motor Company, Dearborn, MI, 48121-2053, USA

SO Int. Conf. Appl. Diamond Films Relat. Mater., 2nd (1993), 229-36.
Editor(s): Yoshikawa, Masanori. Publisher: Scientific Publishing Division of MYU, Tokyo, Japan.
CODEN: 61WDAW

DT Conference

LA English

AB Three thrust areas for automotive application of diamond and diamondlike coatings have been identified and are under active development at Ford. These are: (1) low cost CVD diamond-coated cemented-carbide tools for machining of hypereutectic Al:Si alloys, metal-matrix composites, and reinforced polymer composites, (2) semiconducting diamond sensors for hot or corrosive environments, and (3) diamondlike carbon coatings for

reduced friction and wear of rolling and sliding components. Recent results, prospects and mitations for diamond and **DLC** each of these areas will be discussed.

- L3 ANSWER 15 OF 15 BIOSIS COPYRIGHT 2000 BIOSIS DUPLICATE 6
- AN 1993:160617 BIOSIS
- DN PREV199395081667
- TI Diamond-like carbon coated microporous polycarbonate as a composite barrier for a glucose enzyme electrode.
- AU Higson, Seamus P. J. (1); Vadgama, Pankaj M.
- CS (1) Dep. Med., Univ. Manchester, Hope Hosp., Eccles Old Rd., Salford M6 8HD UK
- SO Analytica Chimica Acta, (1993) Vol. 271, No. 1, pp. 125-133. ISSN: 0003-2670.
- DT Article
- LA English
- Diamond-like carbon (DLC) coated microporous polycarbonate AB membranes were used as outer covering membranes in glucose enzyme electrodes. With optimised DLC deposition and the use of 0.01 mu-m microporous polycarbonate, biocompatability has been seen to improve with only a loss of 6% response after 30 min exposure to whole blood, and a correlation to within 1 mM concentration with a standard laboratory method. In addition, control of the coating process allowed substrate diffusion-limiting properties to the bulk enzyme to be finely tuned permitting extensions in linearity ranges from 5 to gt 80 mM glucose. Furthermore the higher biocompatability coupled with the degree of permselectively exhibited by DLC has enabled operation within whole blood without a second hydrogen peroxide selective barrier membrane. Permeability coefficients of glucose and O-2 determined for corresponding membranes by a classical diffusion chamber technique suggest that both the glucose/O-2 permeability coefficient ratios and the absolute glucose permeability influenced the linearity range.
- => s dlc and (plasmon)
- L4 17 DLC AND (PLASMON)
- => dup rem 14

PROCESSING COMPLETED FOR L4

L5 12 DUP REM L4 (5 DUPLICATES REMOVED)

- => d 15 bib ab 1-12
- L5 ANSWER 1 OF 12 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 1
- AN 2000:347241 CAPLUS
- TI Density, sp3 content and internal layering of **DLC** films by X-ray reflectivity and electron energy loss spectroscopy
- AU LiBassi, A.; Ferrari, A. C.; Stolojan, V.; Tanner, B. K.; Robertson, J.; Brown, L. M.
- CS Department of Physics, University of Durham, Durham, DH1 3LE, UK
- SO Diamond Relat. Mater. (2000), 9(3-6), 771-776 CODEN: DRMTE3; ISSN: 0925-9635
- PB Elsevier Science S.A.
- DT Journal
- LA English
- Ab A variety of hydrogenated and non-hydrogenated amorphous carbon thin films have been characterised by means of grazing-incidence X-ray reflectivity (XRR) to give information about their d., thickness, surface roughness and layering. We used XRR to validate the d. of ta-C, ta-C:H and a-C:H films derived from the valence plasmon in electron energy loss spectroscopy measurements, up to 3.26 and 2.39 g/cm3 for ta-C and ta-C:H, resp. By comparing XRR and electron energy loss spectroscopy (EELS) data, we have been able for the first time to fit a common electron effective mass of m*/me=0.87 for all amorphous carbons and diamond, validating the 'quasi-free' electron approach to d. from valence plasmon energy. While hydrogenated films are found to be substantially uniform in

d. across the film, ta-C films grown by the filtered cathodic vacuum arc (FCVA) show a multilay structure. However, ta-C film from with an S-bend filter show a high uniformity and only a slight dependence on the substrate bias of both sp3 and layering.

RE.CNT 23

RE

- (1) Berger, S; Phil Mag Lett 1988, V57, P285 CAPLUS
- (2) Conway, N; Appl Phys Lett 1998, V73, P2456 CAPLUS
- (3) Davis, C; Phys Rev Lett 1998, V80, P3280 CAPLUS
- (5) Fallon, P; Phys Rev B 1993, V48, P4777 CAPLUS
- (7) Logothetidis, S; Appl Phys Lett 1997, V71, P2463 CAPLUS
- ALL CITATIONS AVAILABLE IN THE RE FORMAT
- L5 ANSWER 2 OF 12 CAPLUS COPYRIGHT 2000 ACS
- AN 2000:187061 CAPLUS
- DN 132:227718
- TI Comparative study of properties of **DLC** films by electron energy loss spectroscopy and X-ray reflectivity
- AU Stolojan, V.; Brown, L. M.; Ferrari, A. C.; Robertson, J.; Bassi, A. Li; Tanner, B. K.
- CS Cavendish Laboratory, University of Cambridge, Cambridge, CB3 OHE, UK
- SO Inst. Phys. Conf. Ser. (1999), 161(Electron Microscopy and Analysis 1999), 361-364
 - CODEN: IPCSEP; ISSN: 0951-3248
- PB Institute of Physics Publishing
- DT Journal
- LA English
- Electron Energy Loss Spectroscopy (EELS) and Grazing Incidence X-Ray AΒ Reflectivity (GIXRR) are techniques employed in the study of the technol. important carbon thin films. In EELS, from the plasmon energy we can obtain the mass d. per contributing valence electron, and the sp2 content is obtained from the normalized intensity of the .pi.* peak in the carbon K-edge. From GIXRR, we can calc. the mass d. per electron and we can obtain information about thickness, roughness and internal layering. The transition from 1s-2p in the sp2-hybridized carbon takes place in a uniaxially anisotropic at. field. This leads the normalized intensity of the .pi.* peak in EELS to be dependent on the convergence conditions and on the orientation of the anisotropy axis relative to the direction of the beam. Our calcns. show this to affect sp2 measurements in amorphous carbon films as well as in graphite, and we find the specific choice of convergence conditions for which this effect is cancelled. By comparing the d. per contributing electron measured from EELS with the d. measured from GIXRR, we can fit an effective mass for the valence electron for all amorphous carbons, which is very nearly that of diamond and we use it to plot a general relationship between sp3 and mass d. for a wide range of hydrogenated and non-hydrogenated carbon films.

RE.CNT 11

RE

- (2) Fallon, P; Diamond Relat Mater 1993, V2, P1004 CAPLUS
- (5) Menon, N; Ultramicroscopy 1998, V74, P83 CAPLUS
- (6) Milani, P; J Appl Phys 1997, V82, P5793 CAPLUS
- (7) Morrison, N; Thin Solid Films 1999, V337, P71 CAPLUS
- (11) Wormington, M; Phil Mag Lett 1996, V74, P211 CAPLUS
- ALL CITATIONS AVAILABLE IN THE RE FORMAT
- L5 ANSWER 3 OF 12 CAPLUS COPYRIGHT 2000 ACS
- AN 1999:795260 CAPLUS
- DN 132:169909
- TI The structural and electron field emission characteristics of pulsed laser deposited diamond-like carbon films with thermal treatment
- AU Jung, H.-S.; Park, H.-H.; Pang, S. S.; Lee, S. Y.
- CS Seodaemoon-ku, Shinchon-dong, 134, Department of Ceramic Engineering, Yonsei University, Seoul, S. Korea
- SO Thin Solid Films (1999), 355-356, 151-156 CODEN: THSFAF; ISSN: 0040-6090
- PB Elsevier Science S.A.
- DT Journal
- LA English
- AB Diamond-like carbon (DLC) films have been deposited on Si(100)

by pulsed laser deposition (PLD) using 355 nm (Nd:YAG) laser. To investigate the factor lat dominates the electron field mission behavior of **DLC** film, structural and elec. properties have been studied as a function of anneal temp. Degrdn. of **DLC** film properties began to be chsd. above 400.degree.C but, in case of **plasmon** energy loss and emission behavior, there were variations of properties at 300.degree.C. From these results, we are convinced that anneal treatment modifies sp3/sp2 bonding ratio in surface as well as bulk of film but the anneal effect is more intensified on the surface than the bulk of **DLC** film. It is also obsd. that the electron field emission property is affected by the modification of sp3/sp2 bonding ratio in the film surface.

RE.CNT 13

RE

- (2) Chuang, F; Appl Phys Lett 1997, V70, P2111 CAPLUS
- (3) Cuomo, J; J Appl Phys 1991, V70, P1706 CAPLUS
- (4) Geis, M; Electron Device Lett 1991, V12, P456 CAPLUS
- (5) Hauser, J; J Non-Cryst Solids 1977, V23, P21 CAPLUS
- (6) Karpman, J; Diam Rel Mater 1994, V4, P10 CAPLUS
- ALL CITATIONS AVAILABLE IN THE RE FORMAT
- L5 ANSWER 4 OF 12 SCISEARCH COPYRIGHT 2000 ISI (R)
- AN 2000:33759 SCISEARCH
- GA The Genuine Article (R) Number: 269WP
- TI The structural and electron field emission characteristics of pulsed laser deposited diamond-like carbon films with thermal treatment
- AU Jung H S; Park H H (Reprint); Pang S S; Lee S Y
- CS YONSEI UNIV, DEPT CERAM ENGN, SEODAEMOON KU, 134 SHINCHON DONG, SEOUL 120749, SOUTH KOREA (Reprint); YONSEI UNIV, DEPT CERAM ENGN, SEODAEMOON KU, SEOUL 120749, SOUTH KOREA; YONSEI UNIV, DEPT ELECT ENGN, SEODAEMOON KU, SEOUL 120749, SOUTH KOREA
- CYA SOUTH KOREA
- SO THIN SOLID FILMS, (NOV 1999) Vol. 356, pp. 151-156.
 Publisher: ELSEVIER SCIENCE SA, PO BOX 564, 1001 LAUSANNE, SWITZERLAND.
 ISSN: 0040-6090.
- DT Article; Journal
- FS PHYS; ENGI
- LA English
- REC Reference Count: 12
 - *ABSTRACT IS AVAILABLE IN THE ALL AND IALL FORMATS*
- Diamond-like carbon (DLC) films have been deposited on Si(100) by pulsed laser deposition (PLD) using 355 nm (Nd:YAG) laser. In order to investigate the factor that dominates the electron field emission behavior of DLC film, structural and electrical properties have been studied as a function of anneal temperature. Degradation of DLC film properties began to be observed above 400 degrees C but, in case of plasmon energy loss and emission behavior, there were variations of properties at 300 degrees C. From these results, we are convinced that anneal treatment modifies sp(3)/sp(2) bonding ratio in surface as well as bulk of film but the anneal effect is more intensified on the surface than the bulk of DLC film. It is also observed that the electron field emission property is affected by the modification of sp(3)/sp(2) bonding ratio in the film surface. (C) 1999 Elsevier Science S.A. All rights reserved.
- L5 ANSWER 5 OF 12 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 2
- AN 1998:10389 CAPLUS
- DN 128:142697
- TI Carbon transport in Si(001) and nucleation of diamond-like carbon layers during mass selected carbon ion beam deposition
- AU Christiansen, S.; Albrecht, M.; Strunk, H. P.; Ronning, C.; Hofsass, H.; Recknagel, E.
- CS Lehrstuhl fur Mikrocharakterisierung, Institut fur Werkstoffwissenschaften, Universitat Erlangen-Nurnberg, Erlangen, 91058, Germany
- SO Diamond Relat. Mater. (1998), 7(1), 15-22 CODEN: DRMTE3; ISSN: 0925-9635
- PB Elsevier Science S.A.
- DT Journal

LA English

AB ·

We investigate the transort of carbon into the Si(001) bstrate during the initial stages of the deposition of amorphous hydrogen-free diamond-like carbon (DLC) films. We employ mass selected ion beams of 50, 100, 500 and 1000 eV 12C+ ions. The microstructures of the produced DLC films, of the substrate and of the interface are characterized by transmission electron microscopy. Electron diffraction exhibits all the DLC films to be amorphous. Parallel electron energy loss spectroscopy shows plasmon peaks at around 30 eV for all room temp. deposited DLC films, which indicates sp3-coordination of C atoms in the amorphous network. Thus amorphous diamond has formed. The Si substrates are affected by the DLC deposition as dependent on the deposition energy. (i) at all energies these are highly strained; after 100 eV deposition they are highly dislocated, (ii) the substrate contains a high amt. of carbon, according to secondary ion mass spectroscopy up to 1 at.%, and (iii) the carbon content is found far beyond a depth of a few nm that is expected for thermal diffusion and for the ion implantation range. We discuss the nucleation and growth of the DLC layer as a function of the deposition energy and find corroboration of the subplantation model. unusually deep-reaching carbon in the substrate is discussed in view of mass transport mechanisms that are enhanced by Si point defects created in excessively high densities due to carbon ion impact.

L5 ANSWER 6 OF 12 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 3

AN 1997:601923 CAPLUS

DN 127:324038

TI Fine structures of valence-band, x-ray-excited Auger electron, and **plasmon** energy loss spectra of diamondlike carbon films obtained using x-ray photoelectron spectroscopy

AU Seo, S.-C.; Ingram, D. C.

CS Condensed Matter and Surface Sciences Program, Department of Physics and Astronomy, Ohio University, Athens, OH, 45701-2979, USA

SO J. Vac. Sci. Technol., A (1997), 15(5), 2579-2584 CODEN: JVTAD6; ISSN: 0734-2101

PB American Institute of Physics

DT Journal

- LA English
- The electronic structures of diamond and graphite using XPS are compared to that of diamond-like carbon (DLC) films that were deposited using unbalanced magnetron sputtering. High resoln. spectra were obtained for the XPS valence-band, x-ray-excited Auger electron (XAES), and photoelectron energy loss. The electronic structures of DLC films are discussed as a function of argon gas pressure and the results are in good agreement with the optical band gap measurement. The XAES spectra from diamond, DLC, and graphite samples show noticeable differences. The XAES N(E) spectra from DLC films contain four carbon KLL transition peaks. The features of the XAES spectra of DLC films are similar to diamond and do not show a graphite-like shoulder. The DLC films deposited at low argon gas pressure show evidence of diamond-like fine structure in the valence-band and photoelectron energy loss spectra, and have wider optical band gaps.
- L5 ANSWER 7 OF 12 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 4

AN 1995:202828 CAPLUS

- DN 122:19538
- TI Electron-energy-loss spectroscopy of mass-selected ion-beam-deposited diamondlike carbon
- AU Kulik, J.; Lifshitz, Y.; Lempert, G. D.; Rabalais, J. W.; Marton, D.
- CS Texas Cent. Superconductivity, Univ. Houston, Houston, TX, 77204, USA
- SO J. Appl. Phys. (1994), 76(9), 5063-9 CODEN: JAPIAU; ISSN: 0021-8979

DT Journal

- LA English
- AB Amorphous diamondlike C (**DLC**) films grown by low-energy mass-selected ion-beam deposition were examd. by EELS. Films grown using deposition energies of 50, 120, and 300 eV were studied. For these deposition energies, all films exhibit similar EELS characteristics indicating a very high degree of sp3 bonding. The bulk **plasmon**

resonance is intermediate between that of graphite and that of diamond; however, the properties of the low-energy-loss spectra the **DLC** films are more similar to those of diamond. The near-K-edge C EELS data from the films exhibit a .pi.* feature which is much smaller than that of graphite or evapd. C. The use of previously proposed computational methods on the near-K-edge EELS data indicates that over 80% of the C atoms are sp3 bonded. The size of the .pi.* feature is larger for smaller **plasmon** energies, as expected. The present data are in accord with other analyses of similar films that indicate a broad (.apprx.30-300 eV) energy window for diamondlike film formation.

- L5 ANSWER 8 OF 12 CAPLUS COPYRIGHT 2000 ACS
- AN 1994:522306 CAPLUS
- DN 121:122306
- TI Electronic density of states and deep defects of hydrogenated amorphous carbon (a-C-H)
- AU Schaefer, J.; Ristein, J.; Ley, L.
- CS Institut fuer Technische Physik, Universitaet Erlangen, Erwin-Rommel-Strasse 1, Erlangen, D-91058, Germany
- SO Diamond Relat. Mater. (1994), 3(4-6), 861-4 CODEN: DRMTE3
- DT Journal
- LA English
- AB R.f. plasma CVD was used to prep. hydrogenated amorphous C (a-C-H) films with properties ranging from polymer-like to diamond-like C (DLC) depending on self bias ranging from 0 to 200 V. The films were characterized by their C ls plasmon loss which yields the d. and by optical properties such as the refractive index and the optical gap which decreases from 4.0 to 1.9 eV on bias. UV photoemission spectra were used to derive relative sp2-contents which increase from 14% for polymer-like material to 37% for DLC. Two defect bands in the pseudogap with binding energies of 1.8 eV and 0.8 eV and an integrated electron d. that increases with bias from 1 .times. 1020 cm-3 to 7 .times. 1020 cm-3 were identified with photoelectron yield spectroscopy. Transient changes in the deep defects of DLC on illumination with 680 nm wavelength light were obsd. and are discussed.
- L5 ANSWER 9 OF 12 SCISEARCH COPYRIGHT 2000 ISI (R)
- AN 94:338897 SCISEARCH
- GA The Genuine Article (R) Number: NN160
- TI ELECTRONIC DENSITY-OF-STATES AND DEEP DEFECTS OF HYDROGENATED AMORPHOUS-CARBON (A-C-H)
- AU SCHAFER J (Reprint); RISTEIN J; LEY L
- CS UNIV ERLANGEN NURNBERG, INST TECH PHYS, ERWIN ROMMEL STR 1, D-91058 ERLANGEN, GERMANY (Reprint)
- CYA GERMANY
- SO DIAMOND AND RELATED MATERIALS, (APR 1994) Vol. 3, No. 4-6, pp. 861-864. ISSN: 0925-9635.
- DT Article; Journal
- FS ENGI
- LA ENGLISH
- REC Reference Count: 12
 - *ABSTRACT IS AVAILABLE IN THE ALL AND IALL FORMATS*
- R.f. plasma chemical vapour deposition was used to prepare hydrogenated amorphous carbon (a-C:H) films with properties ranging from polymer-like to diamond-like carbon (DLC) depending on self bias ranging from 0 to 200 V. The films were characterized by their C 1s plasmon loss which yields the density and by optical properties such as the refractive index and the optical gap which decreases from 4.0 to 1.9 eV on bias. UV photoemission spectra were used to derive relative sp-contents which increase from 14% for polymer-like material to 37% for DLC. Two defect bands in the pseudogap with binding energies of 1.8 eV and 0.8 eV and an integrated electron density that increases with bias from 1 x 10(20) cm-3 to 7 x 10(20) cm-3 were identified with photoelectron yield spectroscopy. Transient changes in the deep defects of DLC on illumination with 680 nm wavelength light were observed and are discussed.
- L5 ANSWER 10 OF 12 CAPLUS COPYRIGHT 2000 ACS
- AN 1994:64898 CAPLUS

DN 120:64898

- TI Electron energy-loss sectral and Raman spectral study diamond and diamond-like carbon films
- AU Sun, Biwu; Xie, Kan; Zhao, Tienan; Liu, Jingqing; Qi, Shangxue; Zhang, Xiaoping; Gao, Ziqiang; Lin, Zhangda
- CS Inst. Phys., Acad. Sin., Beijing, 100080, Peop. Rep. China
- SO Bandaoti Xuebao (1992), 13(11), 653-60 CODEN: PTTPDZ; ISSN: 0253-4177
- DT Journal
- LA Chinese
- Electron energy-loss spectroscopy (EELS) was applied to the anal. of AΒ diamond films (DF), diamond-like films (DLC), and graphite. The main energy-loss peaks for DF are the surface and bulk plasmon energy losses at 23 and 34 eV, resp., and the interband transitions at 5.4 The characteristic energy loss features of DLC are .pi. and (.pi. + .sigma.) electron bulk plasmon energy losses at 4.5 and 22.4 eV, resp., and interband transition of 13 eV. The energy loss peaks for graphite are the .pi. electron plasmon energy loss at 6 eV, interband transition and C-axis plasmon at 13 eV, and energy losses at 20 and 25.6 eV caused by C-axis plasmon and plasmon in the basal plane, resp. The EELS and Raman spectrum of DLC with H were compared with that of DLC without H. The ratios of sp3 to sp2 C sites in DLC both with and without H, and in the second phase DLC of diamond films were calcd. according to the .pi. and (.pi. + .sigma.) electron plasmon energy losses. The ratios of the intensity of .plcnst..omega.p(.sigma.) loss peak were used to est. the relative content of the second phase DLC in diamond films.
- L5 ANSWER 11 OF 12 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 5
- AN 1992:538118 CAPLUS
- DN 117:138118
- TI The structure of highly tetrahedral amorphous diamond-like carbon. III. Study of inhomogeneity by high-resolution inelastic scanning transmission electron microscopy
- AU Yuan, J.; Saeed, A.; Brown, L. M.; Gaskell, P. H.
- CS Cavendish Lab., Univ. Cambridge, Cambridge, CB3 OHE, UK
- SO Philos. Mag. B (1992), 66(2), 187-97 CODEN: PMABDJ; ISSN: 0958-6644
- DT Journal
- LA English
- AB Microscopic inhomogeneity in a highly-tetrahedral amorphous diamond-like carbon (a-DLC) thin film was investigated by high-resoln.

 energy-filtered imaging of inelastically scattered electrons in a scanning transmission electron microscope. The nondiamond-like carbon materials were revealed by their lack of an optical gap, and by their lower-valence plasmon excitation energies. Disk-like carbon inclusions were found embedded in the diamond-like matrix, and were mostly sp2 bonded. The d. of these defects was small, but, in an atypical case, the proportion of nondiamond-like carbon was as high as 50% with two carbon phases closely interwoven. The thin edges of these films were mostly graphitic. The results are discussed with respect to the growth mechanism of a-DLC films.
- L5 ANSWER 12 OF 12 CAPLUS COPYRIGHT 2000 ACS
- AN 1987:204544 CAPLUS
- DN 106:204544
- TI Comparison of the carbon KLL first-derivative Auger spectra from XPS and AES using diamond, graphite, silicon carbide and diamond-like-carbon films
- AU Mizokawa, Yusuke; Miyasato, Tatsuro; Nakamura, Shogo; Geib, Kent M.; Wilmsen, Carl W.
- CS Coll. Integrated Arts Sci., Univ. Osaka Prefect., Sakai, 591, Japan
- SO Surf. Sci. (1987), 182(3), 431-8 CODEN: SUSCAS; ISSN: 0039-6028
- DT Journal
- LA English
- AB The C KLL 1st-deriv. Auger spectra obtained by numerically differentiating the XPS N(E) line gives a better fine-structure fingerprint of the C state than conventional AES. The 1st-deriv. of the x-ray excited (XAES) CKLL

spectrum from a diamond like-C (DLC) film exhibited almost the same spectrum as both XAES and AES spectra from nate I diamond. However, the AES spectrum of the DLC film indicated a graphite-like structure due to electron beam damage. Comparison of the XAES and AES spectra suggested that the electron beam used in conventional AES partially changed the plasmon loss structure of C in diamond, graphite and .beta.-SiC as well.

=> s dlc and waveguide

L6 10 DLC AND WAVEGUIDE

=> dup rem 16

PROCESSING COMPLETED FOR L6

L7 7 DUP REM L6 (3 DUPLICATES REMOVED)

=> d 17 bib ab 1-7

L7 ANSWER 1 OF 7 CAPLUS COPYRIGHT 2000 ACS

AN 1998:614558 CAPLUS

DN 129:237967

TI Apparatus for deposition of diamond-like carbon

IN Sakamoto, Yuichi; Tada, Shigekazu; Saito, Hiroki

PA Nichimen Electronics koken K. K., Japan

SO Jpn. Kokai Tokkyo Koho, 5 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

PΙ

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 10251855	A2	19980922	JP 1997-61263	19970314
JP 3009371	B2	20000214		

- AB In the title app., microwaves travel in a waveguide, go through a window, are guided into a reaction room, and form plasma in the reaction chamber. The inner surface of the window may be concave and a hot air is guided onto the outside surface of the window. Plasma reaction products do not deposit onto the inner surface of the window so that the window is always kept clean because of the hot air.
- L7 ANSWER 2 OF 7 CAPLUS COPYRIGHT 2000 ACS
- AN 1997:747737 CAPLUS
- DN 128:67751
- TI Protective optical coatings
- AU Martinez-Duart, J. M.; Vazquez, L.; Sanchez, O.; Bueno, R. M.; Gutierrez-Llorente, A.; Martin-Palma, R. J.; Garcia-Ayuso, G.
- CS Dept. Fisica Aplicada, Univ. Autonoma de Madrid, Madrid, 28049, Spain
- SO Proc. Int. Conf. Vac. Web Coat. 10th (1996), 170-183. Editor(s): Bakish, Robert. Publisher: Bakish Materials Corp., Englewood, N. J. CODEN: 65IAAF
- DT Conference; General Review
- LA English
- AB At present there are numerous new applications of protective optical coatings as diverse as coatings for the IR, optical coatings on polymeric materials, coatings for power lasers, solar energy conversion systems, waveguides, architectural windows, etc. The mech. properties of these coatings-hardness, stress, adhesion, etc.-have an important role in their performance. Si oxynitrides, diamond, DLC, oxides, Ti nitride, etc. are currently employed as materials for protective optical coatings. Among them, specially important is the case of oxynitride coatings, which can be produced with excellent mech. properties and varying indexes of refraction in the 1.5<n<2.0 interval. These coatings are also excellent for the protection of optical components against the adverse action of moisture. Most of the optical coatings considered in this paper are deposited by advanced techniques operating at relatively low temps. (usually <250.degree.) and producing dense, adherent films with

suitable optical and mach. properties. A review with 22 refs

- L7 ANSWER 3 OF 7 CAPLUS COPYRIGHT 2000 ACS
- AN 1995:678225 CAPLUS
- DN 123:273231
- TI Diamond-like carbon film deposition by super-wide electron-cyclotron resonance plasma source excited by traveling microwave
- AU Ishii, A.; Amadatsu, S.; Sakaguchi, Y.; Minomo, S.; Taniguchi, M.; Sugiyo, M.; Kobayashi, T.
- CS Powersource and Device Department, DAIHEN Corporation, Osaka, 532, Japan
- SO Trans. Mater. Res. Soc. Jpn. (1994), 14B(Magnetic, Fullerene, Dielectric, Ferroelectric, Diamond and Related Materials), 1595-8
 CODEN: TMRJE3
- DT Journal
- LA English
- AB An electron-cyclotron resonance (ECR) plasma source which generates 500 mm wide plasma was developed. The plasma is generated by a 2.45 GHz traveling microwave which is supplied through a long slot antenna prepd. in the waveguide in a divergent magnetic field generated by permanent magnets and a solenoid coil. Diamond-like C (DLC) films were deposited in a wide zone 320 mm in width. The breakdown field was .apprx.8.4 .times. 106 V/cm and permittivity, 3.89. The prepd. Al/DLC/Si metal/insulator/semiconductor (MIS) diode revealed fairly good field effect in its capacitance-voltage curve.
- L7 ANSWER 4 OF 7 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 1
- AN 1994:568241 CAPLUS
- DN 121:168241
- TI Super-wide electron cyclotron resonance plasma source excited by traveling microwave as an efficient tool for diamondlike carbon film deposition
- AU Ishii, A.; Amadatsu, S.; Minomo, S.; Taniguchi, M.; Sugiyo, M.; Sakaguchi, Y.; Kobayashi, T.
- CS Powersource and Device Dep., DAIHEN Corp., Osaka, 532, Japan
- SO J. Vac. Sci. Technol., A (1994), 12(4, Pt. 1), 1241-3 CODEN: JVTAD6; ISSN: 0734-2101
- DT Journal
- LA English
- AB An electron cyclotron resonance (ECR) plasma source which generates 500-mm-wide plasma has been developed. A divergent magnetic field sufficient for ECR is generated by permanent magnets and a solenoid coil. A 2.45-GHz traveling microwave is supplied through a long slot antenna prepd. in the sidewall of the **waveguide** and excites ECR plasma. This app. is applied to the diamondlike carbon (**DLC**) films deposition and **DLC** films were deposited in a wide zone 320 mm in width.
- L7 ANSWER 5 OF 7 CAPLUS COPYRIGHT 2000 ACS DUPLICATE 2
- AN 1994:591682 CAPLUS
- DN 121:191682
- TI Characterization of diamondlike carbon films grown by super-wide electron-cyclotron resonance plasma assisted chemical vapor deposition
- AU Ishii, A.; Amadatsu, S.; Minomo, S.; Taniguchi, M.; Sugiyo, M.; Kobayashi, T.
- CS Powersource and Device Department, DAIHEN Corp., Osaka, 532, Japan
- SO J. Vac. Sci. Technol., A (1994), 12(4, Pt. 1), 1068-71 CODEN: JVTAD6; ISSN: 0734-2101
- DT Journal
- LA English
- AB An electron-cyclotron resonance plasma source that generates 500-mm-wide plasma was developed. The plasma is generated by a 2.45-GHz traveling microwave which is supplied through a long slot antenna prepd. in the waveguide in a divergent magnetic field generated by permanent magnets and a solenoid coil. Diamondlike C (DLC) films were deposited in a zone 320 mm wide. The breakdown field was 8.4 .times. 106 V/cm and permittivity, 3.89. The prepd. Al/DLC/Si MIS diode had a fairly good field effect in its capacitance-voltage curve.
- L7 ANSWER 6 OF 7 CAPLUS COPYRIGHT 2000 ACS

119:83089 Diamond-like carbon fi deposition by super-wide elect TI. resonance plasma source excited by traveling microwave Ishii, Akira; Sakaguchi, Yoshiyuki; Minomo, Shoichiro; Taniguchi, Michio; ΑU Suqiyo, Masato; Kobayashi, Takeshi DAIHEN Corp., Osaka, 532, Japan Jpn. J. Appl. Phys., Part 2 (1993), 32(6A), L802-L805 CS SO CODEN: JAPLD8; ISSN: 0021-4922 DTJournal LA English An electron-cyclotron resonance (ECR) plasma source which generates a long AB and narrow plasma 500 mm in length was developed. The plasma is generated by a 2.45 GHz traveling microwave which is supplied through a slot antenna prepd. in the waveguide in a magnetic field generated by permanent magnets. Diamond-like C (DLC) films were deposited in a wide zone 340 mm in width. The variation of film thickness was less than 10%. The resistivity of the DLC film was .apprx.9.62 .times. 1011 .OMEGA..cm and permittivity 3.63. The prepd. Al/DLC /Si metal/insulator/semiconductor (MIS) diode revealed fairly good field effect in its capacitance-voltage curve. ANSWER 7 OF 7 CAPLUS COPYRIGHT 2000 ACS L7 1991:174539 CAPLUS ΑN 114:174539 DN TIElectron cyclotron resonance radio-frequency hybrid plasma deposited diamondlike carbon as an optical material ΑU Sritharan, S.; Wilson, J. S.; Barbier, P. R.; Pankove, J. I. Optoelectron. Comput. Syst. Cent., Univ. Colorado, Boulder, CO, 80309, USA CS Proc. SPIE-Int. Soc. Opt. Eng. (1990), 1325(Diamond Opt. 3), 253-7 SO CODEN: PSISDG; ISSN: 0277-786X DT Journal LA English Diamondlike carbon (DLC) is deposited by electron cyclotron AΒ resonance radio-frequency (ECR-RF) hybrid plasma method. The films are hard with optical bandgap ranges between 1.1 and 1.8 eV depending on the deposition parameters. Waveguide structures were fabricated in DLC using liftoff technique. The films are also characterized by electron energy loss spectroscopy and Raman spectroscopy. => s dlc and optical properties 148 DLC AND OPTICAL PROPERTIES L8 => s 18 and refractive index L9 36 L8 AND REFRACTIVE INDEX => dup rem 19 PROCESSING COMPLETED FOR L9 29 DUP REM L9 (7 DUPLICATES REMOVED) => s 110 and py<1997 1 FILES SEARCHED... 16 L10 AND PY<1997 L11 => d 111 bib ab 1-16 ANSWER 1 OF 16 CAPLUS COPYRIGHT 2000 ACS L11 1997:659190 CAPLUS ΑN DN 127:339378 ΤI Spectro-ellipsometric studies of structure and optical properties of plasma-grown DLC films Rhee, Sung-Gyu; Lee, Soonil; Oh, Soo-Ghee; Lee, Kwang-Ryeol AU Dep. Phys., Ajou Univ., Suwon, 442-749, S. Korea CS Han'quk Pyomyon Konghak Hoechi (1996), 29(5), 532-539 SO

CODEN: HPKHEL; ISSN: 1225-8024

PB. Korean Institute of Succe Engineering

DT Journal

LA English

AB Diamond-like C (DLC) films were deposited

Diamond-like C (DLC) films were deposited on Si substrates by the plasma decompn. of hydrocarbons under various conditions, and studied by the spectroscopic ellipsometry (SE). The authors used the effective medium approxn. with the dispersion model developed by Forouhi and Bloomer to det. simultaneously both the structure and the optical consts. of the DLC films from their ellipsometric spectra. Esp., the authors studied the variation of the multilayer structure including the interface layer, of the refractive indexes, and of the extinction coeffs. as the deposition conditions were varied; substrate pretreatment procedure, hydrocarbon precursors, and the substrate bias voltage were varied.

L11 ANSWER 2 OF 16 CAPLUS COPYRIGHT 2000 ACS

AN 1997:441065 CAPLUS

DN 127:168275

- TI Study on **optical properties** of diamond-like carbon thin films
- AU Wang, Guihua; Wang, Guangming; Yang, Weiyi
- CS Department of Optical-Electron Technology, Nanjing University of Science and Technology, Nanjing, 210094, Peop. Rep. China
- SO Zhenkong Kexue Yu Jishu (1996), 16(5), 336-341 CODEN: CKKSDV; ISSN: 0253-9748
- PB Zhenkong Kexue Yu Jishu Zazhishe
- DT Journal
- LA Chinese
- AB Diamond-like C [DLC] films were deposited on Ge substrates by radiofrequency-plasma decompn. of CH4. The refractive index, the IR transmittance, and the absorption of the DLC films were studied. The DLC films deposited under various conditions with a refractive index of .apprx.2 were ideal anti-reflection coatings for Ge. FTIR spectroscopy measurements showed that Ge disks coated with DLC films on both sides have a transmittance of 94.5% at the wavelength of 10.6 .mu.m. Ge Disks 100 mm in diam. deposited with DLC films 1.3 .mu.m thick on both sides showed a transmittance of 93.9% at the center and a transmittance of .apprx.92.1% at the 5 spots from the center, showing good uniformity of the films and stability of the coating technique. The absorption coeff. curves at 2.5-25 .mu.m were given by computing programs. The absorption of the DLC films the lowest at .apprx.3.8 .mu. (e.g. .alpha. 10.cm-1 at .lambda. = 3.8 .mu.m) and 600 cm-1 at .lambda. = 10.6 .mu.m. The curve was well explained with valence vibration.
- L11 ANSWER 3 OF 16 CAPLUS COPYRIGHT 2000 ACS
- AN 1996:393418 CAPLUS
- DN 125:100521
- TI Diamond-like carbon films grown by very high frequency (100 MHz) plasma enhanced chemical vapor deposition technique
- AU Kumar, Sushil; Dixit, P. N.; Sarangi, D.; Bhattacharyya, R.
- CS Thin Film and Amorphous Materials Group, National Physical Laboratory, New Delhi, 110 012, India
- SO Appl. Phys. Lett. (1996), 69(1), 49-51 CODEN: APPLAB; ISSN: 0003-6951
- DT Journal
- LA English
- Diamond-like C films were grown by VHF-PECVD technique. Since the self-bias potential developed in a VHF plasma is very low, sufficiently high neg. d.c. voltage was applied to the substrates to make DLC film being grown reasonably hard. Also a comparative study of VHF grown films was made with radio-frequency (13.56 MHz) discharge grown films (grown in the same PECVD reactor). This made it possible to study the specific effects of excitation frequency while keeping other parameters const. Deposition rate (rd) is .apprx.5 times higher for VHF grown films. Marginal variation in optical band gap (Eg) and refractive index (n) were obsd. in VHF grown films with variation in deposition parameters. Max. value of hardness recorded was 1500 kg/mm2 in

the case of radio-frequency and 902 kg/mm2 in the case of VHF grown films, within the range of depition parameters. Stress value were in the range 1.7 .times. 109 - 2.9 .times. 109 Nm-2 for VHF and 3.6 .times. 109 - 4.6 .times. 109 Nm-2 for radio-frequency grown films.

- L11 ANSWER 4 OF 16 CAPLUS COPYRIGHT 2000 ACS
- AN 1996:297175 CAPLUS
- DN 125:72705
- TI Nanocrystalline C = N thin films
- AU Szmidt, J.; Werbowy, A.; Zdunek, K.; Sokowska, A.; Konwerska-Hrabowska, J.; Mitura, S.
- CS Institute of Microelectronics and Optoelectronics, Warsaw University of Technology, Koszykowa 75, Warsaw, 00-662, Pol.
- SO Diamond Relat. Mater. (1996), 5(3-5), 564-569 CODEN: DRMTE3; ISSN: 0925-9635
- DT Journal
- LA English
- This paper discusses phase compn. as well as elec. and optical AΒ properties of carbon-nitrogen (CN) compd. obtained by reactive pulse plasma method. Material produced in such a way is a mixt. of an amorphous compd. which the authors have called polycyanoimine and nanocryst. diamond. Its elec. and optical properties differ from those of **DLC** obtained by the same method. elec. measurements there were not obsd. diode-like current-voltage (I-V) characteristics, what rules out the possibility that nitrogen atoms might act as a dopant in obtained material. Elec. resistivity of studied films, as ranging from 109 to 1011 .OMEGA.cm, was higher than that of **DLC** layers produced from pulse plasma. However, subsequent low temp. (350.degree.) annealing resulted in the drop of their resistivity to the value of 106-107 .OMEGA.cm, the same as for DLC materials. Annealing has also influenced refractive index of studied layers resulting in its increase from 1.9 to 2.13. Also, CN layers produced under the highest nitrogen pressure(i.e. 60 Pa) were luminescent when illuminated with 514.5 nm laser beam, which does not occur in the case of DLC.
- L11 ANSWER 5 OF 16 CAPLUS COPYRIGHT 2000 ACS
- AN 1996:144033 CAPLUS
- DN 124:214755
- TI Determination of stress of **DLC** films from below band gap optical absorption measurements
- AU Basu, M.; Dutta, J.; Chaudhuri, S.; Pal, A. K.; Nakayama, M.
- CS Dep. Mater. Sci., Indian Assoc. Culvit. Sci., Calcutta, 700 032, India
- SO Vacuum (1996), 47(3), 233-8 CODEN: VACUAV; ISSN: 0042-207X
- DT Journal
- LA English
- Diamond like carbon (DLC) films were deposited (thickness AΒ .apprxeq. 100-130 nm) by RF plasma CVD of ethylene on to mica and silicon substrates at room temp. Optical properties of the films deposited at different neg. self bias (VB) voltages (0 to -805 V) were measured. The refractive index (n) and extinction coeff. (k) of DLC films on mica varied within 1.6-2.1and 0.035-0.128, resp. while the band gap energy (Eg) decreased from 2.38 to 2.01 eV with increase in VB from 0 to -805 V. The internal stress (compressive in nature) of these films (on mica) along with that of films deposited by sputtering of vitreous carbon target (on glass) was obtained from the broadening of the optical absorption band tail. The stress on mica (0.2-1.0 GPa) was obsd. to be comparable to the stress on silicon substrates, measured by the flexure of beam technique. The hardness of DLC films on mica varied within 6.5-8 GPa while that on Si varied within 6-9.5 GPa. The hardness of sputtered films on glass substrate was .apprxeq.8.7 GPa.
- L11 ANSWER 6 OF 16 CAPLUS COPYRIGHT 2000 ACS
- AN 1995:1005672 CAPLUS
- DN 124:69993
- TI Precursor gas effect on the mechanical and **optical** properties of ion beam deposited diamond-like carbon films

Oh, Je Uk; Lee, Kwang-Breol; Eun, Kwang Yong
Division of Ceramics, ea Institute of Science and Te ology, P.O. Box
131, Cheongryang, Seoul, 130-650, S. Korea
Thin Solid Films (1995), 270(1-2), 173-6 CS.

SO CODEN: THSFAP; ISSN: 0040-6090

DTJournal

LA English

The effect of precursor gases on the diamond-like C (DLC) film AΒ deposition was studied by the direct ion beam deposition method. DLC films were deposited using methane and benzene as the precursor gases. Ion energies for the deposition range from 100 to 700 eV were achieved by adjusting the beam voltage. The residual stresses, refractive indexes and optical band gaps were compared at the same ion energy. The authors obsd. significant differences in residual stress and optical properties between these films. As in r.f. plasma-assisted CVD, the residual stresses of the films deposited from benzene show a characteristic behavior of lower ion energy deposition than those deposited from methane. The present observations are discussed in terms of the difference in ion energy per C atom at the growth surface. Also the Ar addn. effect on the residual stress is strongly dependent on the precursor gases.

- ANSWER 7 OF 16 CAPLUS COPYRIGHT 2000 ACS L11
- 1995:678221 CAPLUS ΑN

123:271672 DN

- ΤI Electrical and optical properties of pulsed laser ablated diamond-like carbon films
- Leppavuori, S.; Levoska, J. ΑU
- Microelectronics and Material Physics Laboratories, University Oulu, Oulu, CS FIN - 90571, Finland
- Trans. Mater. Res. Soc. Jpn. (1994), 14B(Magnetic, Fullerene, SO Dielectric, Ferroelectric, Diamond and Related Materials), 1579-82 CODEN: TMRJE3
- DT Journal
- LA English
- Amorphous diamond-like C (DLC) thin films were deposited on AΒ fused SiO2 and single crystal Si substrates by pulsed laser ablation using a focused beam from an XeCl excimer laser and a pyrolytic graphite target. The structure and properties of the films were studied by SEM, x-ray diffraction, micro-Raman and FTIR spectroscopy, elec. cond. and optical measurements. By varying the peak power d. of the laser beam 109-1010 W/cm2 and the deposition temp. between room temp. and 200.degree. it is possible to tailor the properties of the deposited films between the extremes of diamond-like and graphite-like C. The optical band gap of the films varied from zero (graphite-like films) to a max. value of 1.35 eV (DLC). By introducing H into the chamber during deposition, the DLC band gap could be increased to 2.2 eV. The real part (n) of the visible wavelength refractive index ranged 2.4-2.5 for good quality DLC films. The imaginary part (k) of the refractive index was highest at short wavelengths, and reduced when approaching the near-IR region. It was possible to vary the elec. cond. of the unhydrogenated films by 8 orders of magnitude between DLC and graphite-like material. The cond. of the DLC films exhibited an exp(-T-1/4) dependence on temp. which is characteristic for amorphous semiconductors.
- ANSWER 8 OF 16 CAPLUS COPYRIGHT 2000 ACS L11
- 1995:364647 CAPLUS ΑN
- DN 122:227710
- ΤI Effect of laser power density and deposition temperature on electrical and optical properties of pulsed laser ablated diamond-like carbon films
- ΑU Levoska, J.; Leppaevuori, S.
- Microelectronics and Material Physics Laboratories, University of Oulu, CS P.O. Box 400, Oulu, FIN-90571, Finland
- SO Appl. Surf. Sci. (1995), 86(1-4), 180-4 CODEN: ASUSEE; ISSN: 0169-4332
- DT Journal
- English LA

Amorphous diamond-like (DLC) thin films were deposited by pulsed laser ablation mg an XeCl excimer laser and a rolytic graphite target. The effect of the laser power d. and the substrate temp. on the AB optical and elec. properties of the films was studied. It is possible to tailor the elec. and optical properties of the deposited films between diamond-like and graphite-like by varying the peak power d. of the laser beam and the deposition temp. The optical band gap of the films varied from zero (deposition temp. .gtoreq.200.degree.) to a max. value of 1.35 eV. The real part n of the visible wavelength refractive index ranged from 2.4 to 2.5 for good quality DLC films. It was possible to vary the elec. cond. by eight orders of magnitude between DLC and graphite-like material. cond. of the DLC films exhibited an exp(-T-1/4) dependence on temp. that is characteristic of hopping mechanisms; graphite-like films showed more band-type cond.

- L11 ANSWER 9 OF 16 CAPLUS COPYRIGHT 2000 ACS
- 1994:522306 CAPLUS AN
- DN 121:122306
- Electronic density of states and deep defects of hydrogenated amorphous TΙ carbon (a-C-H)
- ΑU Schaefer, J.; Ristein, J.; Ley, L.
- Institut fuer Technische Physik, Universitaet Erlangen, CS Erwin-Rommel-Strasse 1, Erlangen, D-91058, Germany
- Diamond Relat. Mater. (1994), 3(4-6), 861-4 SO CODEN: DRMTE3
- DT Journal
- LA English
- R.f. plasma CVD was used to prep. hydrogenated amorphous C (a-C-H) films AΒ with properties ranging from polymer-like to diamond-like C (DLC) depending on self bias ranging from 0 to 200 V. The films were characterized by their C 1s plasmon loss which yields the d. and by optical properties such as the refractive index and the optical gap which decreases from 4.0 to 1.9 eV on bias. UV photoemission spectra were used to derive relative sp2-contents which increase from 14% for polymer-like material to 37% for ${\tt DLC}$ Two defect bands in the pseudogap with binding energies of 1.8 eV and 0.8 eV and an integrated electron d. that increases with bias from 1 .times. 1020 cm-3 to 7 .times. 1020 cm-3 were identified with photoelectron yield spectroscopy. Transient changes in the deep defects of DLC on illumination with 680 nm wavelength light were obsd. and are discussed.
- L11 ANSWER 10 OF 16 CAPLUS COPYRIGHT 2000 ACS
- AN 1994:110732 CAPLUS
- 120:110732 DN
- Study of the optical properties of diamond-like TΙ coatings prepared by laser-arc
- Scheibe, H. J.; Ristau, D.; Rahe, M. ΑU
- Fraunhofer Einrichtung Werkstoffphys. Schichttechnol., Dresden, 0-8027, CS Germany
- Diamond Relat. Mater. (1993), 2(11), 1424-9 SO CODEN: DRMTE3
- DT Journal
- English LA
- The laser-arc as a controlled pulsed arc plasma source was used to prep. AΒ diamond-like C coatings (DLC) for optical applications. DLC films with a thickness of .ltoreq.500 nm were deposited on different substrate materials (ZnSe, NaCl, KCl, Ge) using special prepn. techniques for enhancing the substrate-film adhesion. Coating was performed at room temp. in a vacuum of 10-4 Pa. A special moving substrate holder was used to deposit an all-round protective DLC that covered the complete surface of the salt substrates including the rims. The optical properties of the coating were detd. by spectrophotometry and laser calorimetry. The refractive indexes were calcd. based on the photometric transmission measurements. The optical absorption at 10.6 .mu.m ranges from 200 to 900/cm, and depends on the film thickness and on the substrate material. The results demonstrate that the controlled arc evapn. by laser-arc is

suitable for the prepn of **DLC** with optical quality.

L11 ANSWER 11 OF 16 CAPLUS COPYRIGHT 2000 ACS

AN 1992:48137 CAPLUS

DN 116:48137

TI Investigation on the **DLC** films prepared by dual-ion beam sputtering deposition

AU Wang, Tianmin; Wang, Weijie; Liu, Guidng; Huang, Liangpu; Luo, Chuntai; Liu, Dingquan; Xu, Ming; Yang, Yimin

CS Dep. Mater. Sci., Lanzhou Univ., Lanzhou, 730001, Peop. Rep. China

SO Proc. SPIE-Int. Soc. Opt. Eng. (1991), 1519(Int. Conf. Thin Film Phys. Appl., 1991, Pt. 2), 890-900 CODEN: PSISDG; ISSN: 0277-786X

DT Journal

LA English

AΒ

Diamond-like C (DLC) films were successfully deposited onto Si, glass, Mo and stainless steel substrates at <50.degree. by dual-ion beam sputtering deposition. The influences of the bombarding ion beam energy, the bombarding ion beam c.d. and the ratio of H to Ar gas flow in the bombarding ion source on the properties and structures of films were investigated. The deposited films are composed of SP3 bond and SP2 bonds with bond-angle disorder. Depending on processing parameters and substrate, the predominant phase would be amorphous C, micrographite crystals or microcubic diamond crystals. With an increase of the parameters described above the elec. resistivity of the films and the relative transmittance vs. wavelength curves of deposited glasses in IR region (1.5-5.5 .mu.m) have tendency to increase 1st and then to decrease. The resistivities of the films deposited on Si, Mo and stainless steel range from 107 to 1012 .OMEGA. cm. While on glass substrate, the square elec. resistivity varies from 105 to 109 .OMEGA./.box., the ${\bf refractive~index}$ ranges from 1.1 to 2.6. The films and substrate have good adhesion force and the values between films and Si, Mo substrate are about 8-14 kg/mm2.

L11 ANSWER 12 OF 16 CAPLUS COPYRIGHT 2000 ACS

AN 1991:255889 CAPLUS

DN 114:255889

 ${
m TI}$ Properties of reactively-deposited silicon carbide (SiC) and germanium carbide (GeC) alloys

AU Martin, P. M.; Johnston, J. W.; Bennett, W. D.

CS Pac. Northwest Lab., Richland, WA, 99352, USA

SO Proc. SPIE-Int. Soc. Opt. Eng. (1990), 1323(Opt. Thin Films 3), 291-8
CODEN: PSISDG; ISSN: 0277-786X

DT Journal

LA English

Thin-film SixC1-x and GexC1-x alloy coatings with low IR optical AB absorption were fabricated by d.c.- and radiofrequency-reactive magnetron sputtering. The optical and mech. properties of the coatings depend on compn. detd. by deposition conditions. The refractive index and optical absorption coeff. of SixC1-x alloys were varied from those of amorphous Si to those near diamond-like C (DLC) by increasing C content. The band edge shifted <1.2 eV with C content as .ltoreq.0.8. The useful range of the SixCl-x coatings was extended to wavelengths .gtoreq.1 .mu.m. The useful transparency range of GexC1-xcoatings is 3-12 .mu.m. The refractive index of GexCl-x coatings was varied from 4.2 of amorphous Ge to near 3.4 by increasing x from 0 to 0.5. The optical absorption coeff. was a complex function of compn. and C-H, Ge-H, and Ge-C bonding. Mech. stress in both materials was generally moderate, and increased with increasing C content for the GeC alloys and decreased with increasing C for the SiC alloys. The wide range of optical properties obtainable for both coating types makes them useful in many types of multilayer designs. Abrasion-resistant IR multispectral antireflection coatings on ZnS were demonstrated using Ge0.9C0.1 and DLC layers.

AN 1989:643818 CAPLUS

DN 111:243818

L11 ANSWER 13 OF 16 CAPLUS COPYRIGHT 2000 ACS

TI Synthesis and characterization of diamond-like carbon films using ion beam technique

AU Wu, Richard L. C.

CS Universal Energy Syst., Inc., Dayton, OH, 45432, USA

SO Mater. Res. Soc. Symp. Proc. (1989), 152(Opt. Mater.: Process. Sci.), 33-7
CODEN: MRSPDH; ISSN: 0272-9172

DT Journal

LA English

Diamond-like carbon (DLC) coatings were deposited on several IR transmitting substrates utilizing the ion beam deposition technique. Optimum deposition parameters were established as a function of source gas compn., source pressure, ion-impact energy, substrate material and cleaning substrate procedures. Extensive characterization of the DLC films was also performed. Rutherford backscattering and proton recoil techniques were used to analyze C and H content and impurities. These films contain 70% at. C and 30% at. H. Transmission electron microscopy was used to analyze the crystallinity, void structure and surface microstructure, which were found to be amorphous and dense.

Optical properties, such as refractive index and extinction coeff., were measured using

transmission/reflection spectroscopy, ellipsometry and laser calorimetry. Environmental testing was performed using various acids and solvents. The thermal stability and moisture penetration on these **DLC** films were extensively investigated. The effect of high ion energy radiation on **DLC** films was studied. Details of the prepn. method and characterization of **DLC** films are presented.

L11 ANSWER 14 OF 16 CAPLUS COPYRIGHT 2000 ACS

AN 1976:127990 CAPLUS

DN 84:127990

TI Anodic behavior of iron in sodium sulfate solutions containing fatty acids

AU Mrowczynski, G.; Szklarska-Smialowska, Susan

CS Inst. Phys. Chem., Pol. Acad. Sci., Warsaw, Pol.

SO Br. Corros. J. (1975), 10(4), 192-5 CODEN: BCRJA3

DT Journal

LA English

AΒ The effect of some fatty acids (caproic, caprylic, capric) on the anodic behavior of Fe in de-aerated 0.cntdot.05M Na2SO4 solns. of pH 6-12 was studied by ellipsometry and by measurements of the double layer capacitance (${ t dlc}$). At certain concns. of added fatty acids (e.g., caprylic acid at a concn. of 2 .times. 10-2 mole/1.) the rate of anodic dissoln. of Fe and the dlc are both decreased. The most efficient inhibition is obsd. at pH 6. The surface films formed in solns. at pH 6 exhibit complex indices of refraction, n = (2.6 .+-. 0.2) $\{1-(0.16i .+-. 0.02i)\}$ and grow according to a log. law. optical properties and film growth kinetics are found for films formed in similar solns. at pH 12. These films are composed of Fe oxide. At potentials below 500 mVvs. normal H electrode , an increase of pH in the range 6-10 causes a decrease in inhibitive efficiency of the fatty acids, an increase of dlc, and the formation of non-protective films with low refractive indices. At potentials above 500 mV the surface films are protective irrespective of the pH of the soln.

- L11 ANSWER 15 OF 16 SCISEARCH COPYRIGHT 2000 ISI (R)
- AN 95:662490 SCISEARCH
- GA The Genuine Article (R) Number: RV828
- TI DIAMOND-LIKE CARBON-FILMS GROWN USING A SADDLE FIELD SOURCE
- AU PANWAR O S (Reprint); SARANGI D; KUMAR S; DIXIT P N; BHATTACHARYYA R
- CS NATL PHYS LAB, THIN FILM & AMORPHOUS MAT GRP, DR KS KRISHNAN RD, NEW DELHI 110012, INDIA (Reprint)
- CYA INDIA
- JOURNAL OF VACUUM SCIENCE & TECHNOLOGY A-VACUUM SURFACES AND FILMS, (SEP/OCT 1995) Vol. 13, No. 5, pp. 2519-2524.
 ISSN: 0734-2101.
- DT Article; Journal
- FS PHYS; ENGI

LA ENGLISH Reference Count: 26 *ABSTRACT IS AVAILABLE IN THE ALL AND IALL FORMATS* This article reports the measurement of deposition rate, dark AΒ conductivity versus temperature, optical band gap, refractive index, extinction coefficient, hardness, adhesion, and internal stress of diamond-like carbon (DLC) films grown by aspirating hydrocarbon gases (CH4 and C2H2) and C6H6 vapors into a saddle field source. The source operates at 0.7-1.0 kV in the pressure range of $1.0 \times 10(-4) - 7.0 \times 10(-4)$ Torr and is of a modular design to cover increasingly larger areas. DLC films have been grown for the first time using CH4 by this technique. The effect of source to substrate distance on the deposition rate and uniformity of the films has been studied at varying bower to the source using C2H2 gas. The films are found to be hard and they adhere well to 7059 glass, quartz, silicon, Mo, and Mylar substrates. Though the deposition rate increases with increasing power and with increasing carbon to hydrogen ratio of the hydrocarbon feedstock, the material properties are relatively independent of the type of hydrocarbon used. (C) 1995 American Vacuum Society. L11 ANSWER 16 OF 16 SCISEARCH COPYRIGHT 2000 ISI (R) 94:338897 SCISEARCH ΑN The Genuine Article (R) Number: NN160 GΑ ELECTRONIC DENSITY-OF-STATES AND DEEP DEFECTS OF HYDROGENATED ΤI AMORPHOUS-CARBON (A-C-H) ΑU SCHAFER J (Reprint); RISTEIN J; LEY L UNIV ERLANGEN NURNBERG, INST TECH PHYS, ERWIN ROMMEL STR 1, D-91058 CS ERLANGEN, GERMANY (Reprint) CYA GERMANY DIAMOND AND RELATED MATERIALS, (APR 1994) Vol. 3, No. 4-6, pp. SO 861-864. ISSN: 0925-9635. DTArticle; Journal FSENGI ENGLISH LA REC Reference Count: 12 *ABSTRACT IS AVAILABLE IN THE ALL AND IALL FORMATS* AΒ R.f. plasma chemical vapour deposition was used to prepare hydrogenated amorphous carbon (a-C:H) films with properties ranging from polymer-like to diamond-like carbon (DLC) depending on self bias ranging from 0 to 200 V. The films were characterized by their C 1s plasmon loss which yields the density and by optical properties such as the refractive index and the optical gap which decreases from 4.0 to 1.9 eV on bias. UV photoemission spectra were used to derive relative sp-contents which increase from 14% for polymer-like material to 37% for DLC. Two defect bands in the pseudogap with binding energies of 1.8 eV and 0.8 eV and an integrated electron density that increases with bias from 1 x 10(20) cm-3 to 7 x 10(20) cm-3 were identified with photoelectron yield spectroscopy. Transient changes in the deep defects of DLC on illumination with 680 nm wavelength light were observed and are discussed. => d his (FILE 'HOME' ENTERED AT 14:27:22 ON 22 JUN 2000) FILE 'BIOSIS, CAPLUS, MEDLINE, SCISEARCH' ENTERED AT 14:27:47 ON 22 JUN 2000 21 S DLC AND (SENSOR OR BIOSENSOR) L1O S L1 AND (WAVEGUIDE OR OPTIC? OR SPR OR PLASMON) L215 DUP REM L1 (6 DUPLICATES REMOVED) L3 17 S DLC AND (PLASMON) L4

12 DUP REM L4 (5 DUPLICATES REMOVED)

7 DUP REM L6 (3 DUPLICATES REMOVED)

148 S DLC AND OPTICAL PROPERTIES

36 S L8 AND REFRACTIVE INDEX

10 S DLC AND WAVEGUIDE

L5

L6 L7

1.8

L9

```
29 DUP REM L9 __DUPLICATES REMOVED)
L10
            16 S L10 AND F
L11
                             997
=> s 18 and porous?
            0 L8 AND POROUS?
L12
=> s 18 and poro?
            0 L8 AND PORO?
L13
=> s 18 and membrane
L14
            0 L8 AND MEMBRANE
=> s dlc and poro?
           32 DLC AND PORO?
1.15
=> d 17 and (membrane or opti? or waveg?)
'AND' IS NOT A VALID FORMAT FOR FILE 'CAPLUS'
'(MEMBRANE;OR;OPTI?;OR;WAVEG?)' IS NOT A VALID FORMAT FOR FILE 'CAPLUS'
The following are valid formats:
ABS ----- GI and AB
ALL ----- BIB, AB, IND, RE
APPS ----- AI, PRAI
BIB ----- AN, plus Bibliographic Data and PI table (default)
CAN ----- List of CA abstract numbers without answer numbers
CBIB ----- AN, plus Compressed Bibliographic Data
DALL ----- ALL, delimited (end of each field identified)
DMAX ----- MAX, delimited for post-processing
FAM ----- AN, PI and PRAI in table, plus Patent Family data
FBIB ----- AN, BIB, plus Patent FAM
IND ----- Indexing data
IPC ----- International Patent Classifications
MAX ----- ALL, plus Patent FAM, RE
PATS ----- PI, SO
SAM ----- CC, SX, TI, ST, IT
SCAN ----- CC, SX, TI, ST, IT (random display, no answer numbers;
             SCAN must be entered on the same line as the DISPLAY,
             e.g., D SCAN or DISPLAY SCAN)
STD ----- BIB, IPC, and NCL
IABS ----- ABS, indented with text labels
IALL ----- ALL, indented with text labels
IBIB ----- BIB, indented with text labels
IMAX ----- MAX, indented with text labels
ISTD ----- STD, indented with text labels
OBIB ---- AN, plus Bibliographic Data (original)
OIBIB ----- OBIB, indented with text labels
SBIB ----- BIB, no citations
SIBIB ----- IBIB, no citations
HIT ---- Fields containing hit terms
HITIND ----- IC, ICA, ICI, NCL, CC and index field (ST and IT)
             containing hit terms
HITRN ----- HIT RN and its text modification
HITSTR ----- HIT RN, its text modification, its CA index name, and
             its structure diagram
FHITSTR ---- First HIT RN, its text modification, its CA index name, and
             its structure diagram
KWIC ----- Hit term plus 20 words on either side
```

OCC ----- Number of occurrence of hit term and field in which it occurs

To display a particular field or fields, enter the display field codes. For a list of the delay field codes, enter HELP DF DS at an arrow prompt (=>). Examples of formats include: TI; TI,AU; BIB,ST; TI,IND; TI,SO. You may specify the format fields in any order and the information will be displayed in the same order as the format specification.

All of the formats (except for SAM, SCAN, HIT, HITIND, HITRN, HITSTR, FHITSTR, KWIC, and OCC) may be used with DISPLAY ACC to view a specified Accession Number. ENTER DISPLAY FORMAT (BIB):

ENTER DISPLAY FORMAT (BIB):bib

```
L7 ANSWER 1 OF 7 CAPLUS COPYRIGHT 2000 ACS
```

AN 1998:614558 CAPLUS

DN 129:237967

TI Apparatus for deposition of diamond-like carbon

IN Sakamoto, Yuichi; Tada, Shigekazu; Saito, Hiroki

PA Nichimen Electronics koken K. K., Japan

SO Jpn. Kokai Tokkyo Koho, 5 pp.

CODEN: JKXXAF

DT Patent

LA Japanese

FAN.CNT 1

	PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
			-		
PΙ	JP 10251855	A2	19980922	JP 1997-61263	19970314
	JP 3009371	В2	20000214		

=> s 17 and (membrane or opti? or waveg?)

L16 7 L7 AND (MEMBRANE OR OPTI? OR WAVEG?)

=> s 115 and (membrane or opti? or waveg?)

L17 2 L15 AND (MEMBRANE OR OPTI? OR WAVEG?)

=> d bib ab 1-2

L17 ANSWER 1 OF 2 CAPLUS COPYRIGHT 2000 ACS

AN 1997:73052 CAPLUS

DN 126:121365

TI The electrochemical and wear behavior of amorphous diamond-like carbon coatings and multilayered coatings in aqueous environments

AU Drees, D.; Celis, J. P.; Dekempeneer, E.; Meneve, J.

CS Dep. MTM KULeuven, Louvain, B-3001, Belg.

SO Surf. Coat. Technol. (1996), 86-87(1-3), 575-580 CODEN: SCTEEJ; ISSN: 0257-8972

PB Elsevier

DT Journal

LA English

AB R.f. plasma CVD deposited diamond-like carbon coatings l(DLC) possess interesting wear properties in dry testing conditions or in vacuum applications. Extremely low friction coeffs. are displayed in dry test conditions, the friction coeff. being dependent on relative humidity and presence of oxygen. The question arises whether these coatings are equally effective in an aq. medium. Parameters controlling the through-coating porosity are discussed and their relative importance indicated. A coulometric quant. porosity measurement has been used. Characterization by light optical microscopy, profilometric measurements and EMPA suggest the importance of the microstructure of the substrate material. Further, pin-on-disk wear tests in water slow a detrimental damage when compared to dry wear tests. De-adhesion of the coating occurs in an early stage with subsequently a rapid destruction of the coating. Important parameters in this failure

mechanism are the initial contact stress and the development of this stress by initial wear

L17 ANSWER 2 OF 2 SCISEARCH COPYRIGHT 2000 ISI (R)

AN 97:64469 SCISEARCH

GA The Genuine Article (R) Number: WC006

TI The electrochemical and wear behaviour of amorphous diamond-like carbon coatings and multilayered coatings in aqueous environments

AU Drees D (Reprint); Celis J P; Dekempeneer E; Meneve J

CS KATHOLIEKE UNIV LEUVEN, DEPT MTM, DE CROYLAAN 2, B-3001 LOUVAIN, BELGIUM (Reprint); VLAASME INSTELLING TECHNOL ONDERZOEK, B-2400 MOL, BELGIUM

CYA BELGIUM

SO SURFACE & COATINGS TECHNOLOGY, (15 DEC 1996) Vol. 86-7, No. 1-3, Part 2, pp. 575-580.

Publisher: ELSEVIER SCIENCE SA LAUSANNE, PO BOX 564, 1001 LAUSANNE 1, SWITZERLAND.

ISSN: 0257-8972.

DT Article; Journal

FS ENGI

AΒ

LA English

REC Reference Count: 9

ABSTRACT IS AVAILABLE IN THE ALL AND IALL FORMATS

R.f. plasma CVD deposited diamond-like carbon coatings (DLC) possess interesting wear properties in dry testing conditions or in vacuum applications. Extremely low friction coefficients are displayed in dry test conditions, the friction coefficient being dependent on relative humidity and presence of oxygen. The question arises whether these coatings are equally effective in an aqueous medium. Parameters controlling the through-coating porosity are discussed and their relative importance indicated. A coulometric quantitative porosity measurement has been used. Characterisation by light optical microscopy, profilometric measurements and EPMA suggest the importance of the microstructure of the substrate material. Further, pin-on-disk wear tests in water show a detrimental damage when compared to dry wear tests. De-adhesion of the coating occurs in an early stage with subsequently a rapid destruction of the coating. Important parameters in this failure mechanism are the initial contact stress and the development of this stress by initial wear.

=> log y

COST IN U.S. DOLLARS	SINCE FILE ENTRY	TOTAL SESSION
FULL ESTIMATED COST	177.44	177.59
DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)	SINCE FILE ENTRY	TOTAL SESSION
CA SUBSCRIBER PRICE	-25.60	-25.60

STN INTERNATIONAL LOGOFF AT 14:49:23 ON 22 JUN 2000